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#### October 2013

### FDME510PZT P-Channel PowerTrench<sup>®</sup> MOSFET -20 V, -6 A, 37 m $\Omega$

#### Features

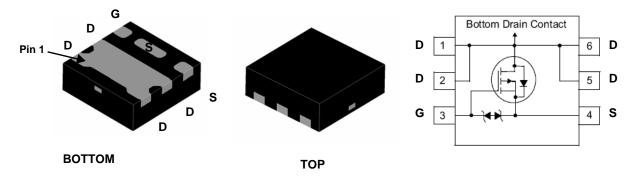
- Max  $r_{DS(on)} = 37 \text{ m}\Omega$  at  $V_{GS} = -4.5 \text{ V}$ ,  $I_D = -5 \text{ A}$
- Max  $r_{DS(on)} = 50 \text{ m}\Omega$  at  $V_{GS} = -2.5 \text{ V}$ ,  $I_D = -4 \text{ A}$
- Max  $r_{DS(on)} = 65 \text{ m}\Omega$  at  $V_{GS} = -1.8 \text{ V}$ ,  $I_D = -3 \text{ A}$
- Max  $r_{DS(on)}$  = 100 m $\Omega$  at V<sub>GS</sub> = -1.5 V, I<sub>D</sub> = -2 A
- Low profile: 0.55 mm maximum in the new package MicroFET 1.6x1.6 Thin
- Free from halogenated compounds and antimony oxides
- HBM ESD protection level > 2400V (Note3)
- RoHS Compliant



#### **General Description**

This device is designed specifically for battery charging or load switching in cellular handset and other ultraportable applications. It features a MOSFET with low on-state resistance.

The MicroFET 1.6x1.6 **Thin** package offers exceptional thermal performance for its physical size and is well suited to switching and linear mode applications.



MicroFET 1.6x1.6 Thin

#### MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol	Paramet		Ratings	Units		
V <sub>DS</sub>	Drain to Source Voltage		-20	V		
V <sub>GS</sub>	Gate to Source Voltage			±8	V	
I <sub>D</sub>	Drain Current -Continuous	T <sub>A</sub> = 25 °C	(Note 1a)	-6	•	
	-Pulsed			-15	Α	
P <sub>D</sub>	Power Dissipation for Single Operation	T <sub>A</sub> = 25 °C	(Note 1a)	2.1	14/	
	Power Dissipation for Single Operation	T <sub>A</sub> = 25 °C	(Note 1b)	0.7	W	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range			-55 to +150	°C	

#### **Thermal Characteristics**

$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	60	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	175	0/10

#### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
7T	FDME510PZT	MicroFET 1.6x1.6 Thin	7 "	8 mm	5000 units

DME51
<b>IOPZT</b>
P-Cha
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SFET

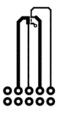
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	acteristics					
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = -250 μA, V <sub>GS</sub> = 0 V	-20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$ , referenced to 25 °C		-13		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = -16 V, V <sub>GS</sub> = 0 V			-1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μA
On Chara	acteristics					
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = -250 \ \mu A$	-0.4	-0.5	-1.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D$ = -250 $\mu$ A, referenced to 25 °C		3		mV/°C
	Drain to Source On Resistance	$V_{GS} = -4.5 \text{ V}, I_D = -5 \text{ A}$		31	37	
		$V_{GS} = -2.5 \text{ V}, I_D = -4 \text{ A}$		38	50	mΩ
r <sub>DS(on)</sub>		$V_{GS} = -1.8 \text{ V}, I_D = -3 \text{ A}$		48	65	
		$V_{GS} = -1.5 \text{ V}, \ I_D = -2 \text{ A}$		57	100	
		$V_{GS} = -4.5 \text{ V}, \ I_D = -5 \text{ A}, \ T_J = 125 \ ^{\circ}\text{C}$		40	60	
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = -5 V, I_{D} = -5 A$		21		S
Dynamic	Characteristics					
C <sub>iss</sub>	Input Capacitance			1120	1490	pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0 V, f = 1 MHz		155	210	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			140	210	pF
Switching	g Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time	$V_{DD} = -10 \text{ V}, \text{ I}_{D} = -5 \text{ A}$		6.5	13	ns
t <sub>r</sub>	Rise Time			10	16	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$-$ V <sub>GS</sub> = -4.5 V, R <sub>GEN</sub> = 6 $\Omega$		93	149	ns
t <sub>f</sub>	Fall Time			54	86	ns
Q <sub>g</sub>	Total Gate Charge			16	22	nC
Q <sub>gs</sub>	Gate to Source Gate Charge	— V <sub>DD</sub> = -10 V, I <sub>D</sub> = -5 A — V <sub>GS</sub> = -4.5 V		1.6		nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge	* GS = *		4		nC

V <sub>SD</sub>	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = -1.6 A$ (Note 2)		-0.6	-1.2	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = -5 A, di/dt = 100 A/μs		38	61	ns
Q <sub>rr</sub>	Reverse Recovery Charge			16	29	nC

Notes: 1. R<sub>0JA</sub> is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R<sub>0JC</sub> is guaranteed by design while R<sub>0CA</sub> is determined by the user's board design.



a. 60 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.



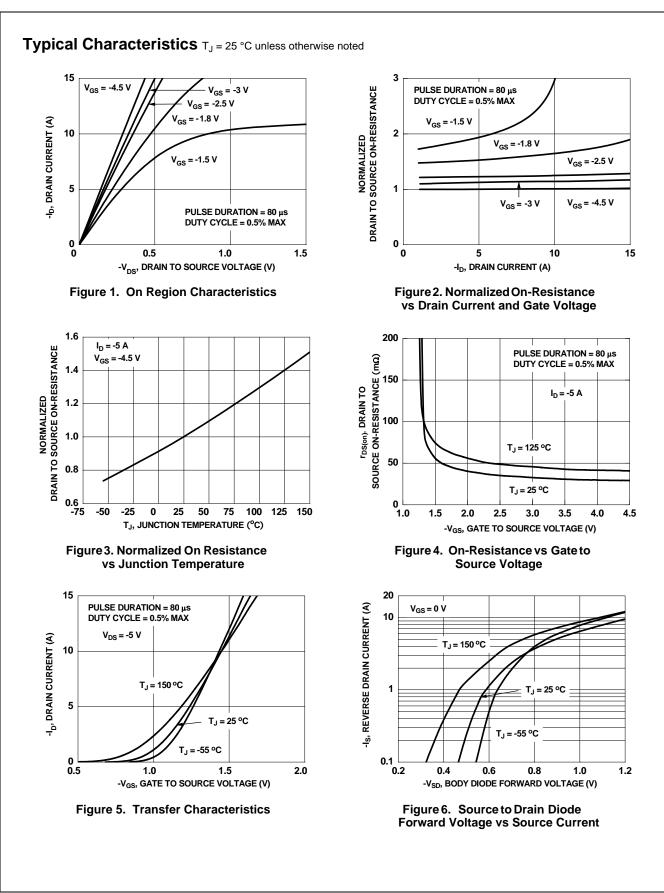
b. 175 °C/W when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300 $\mu$ s, Duty cycle < 2.0%.

3. The diode connected between the gate and source serves only as protection ESD. No gate overvoltage rating is implied.

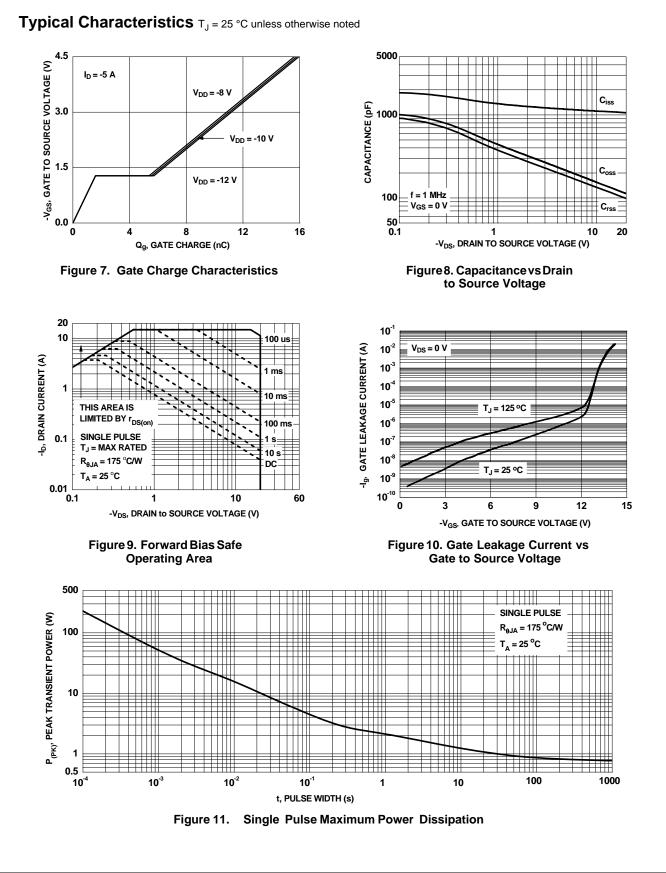
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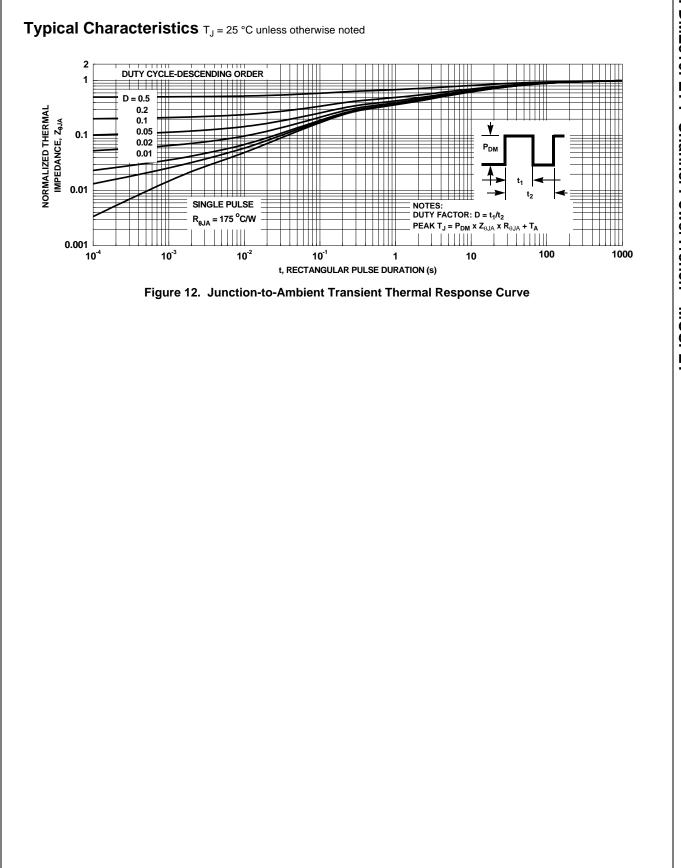


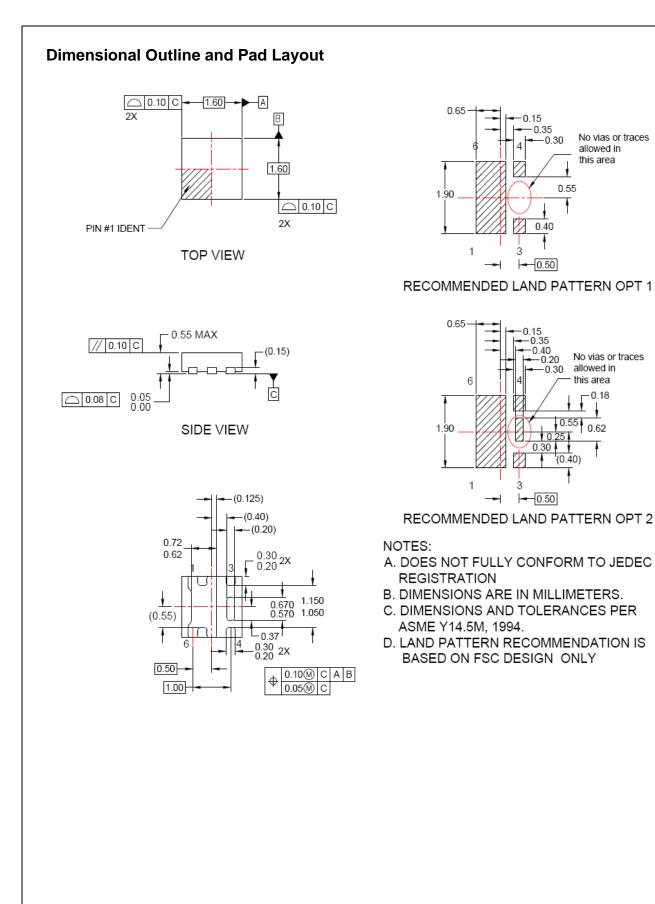
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0.65

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1

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No vias or traces

allowed in

this area

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allowed in this area





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